

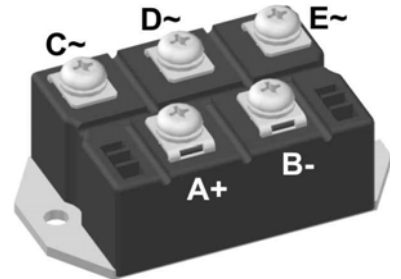
# Standard Rectifier Module

|                           |
|---------------------------|
| <b>3~<br/>Rectifier</b>   |
| $V_{RRM} = 1200\text{ V}$ |
| $I_{DAV} = 125\text{ A}$  |
| $I_{FSM} = 1200\text{ A}$ |

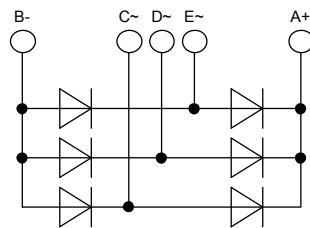
## 3~ Rectifier Bridge

Part number

**VUO110-12N07**



E72873



### Features / Advantages:

- Package with DCB ceramic
- Improved temperature and power cycling
- Planar passivated chips
- Very low forward voltage drop
- Very low leakage current

### Applications:

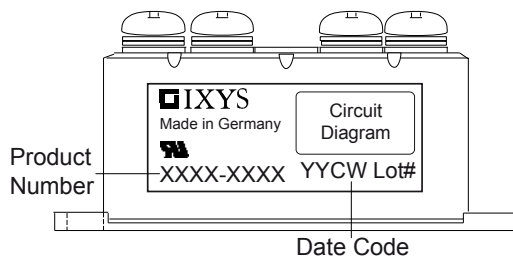
- Diode for main rectification
- For three phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

### Package: PWS-E

- Industry standard outline
- RoHS compliant
- Easy to mount with two screws
- Base plate: Copper internally DCB isolated
- Advanced power cycling

| Rectifier  |  |   |                         | Ratings |      |                   |  |
|------------|--|---|-------------------------|---------|------|-------------------|--|
| Symbol     | Definition                                   | Conditions  | min.                    | typ.    | max. | Unit              |  |
| $V_{RSM}$  | max. non-repetitive reverse blocking voltage | $T_{VJ} = 25^{\circ}C$                                |                         |         | 1300 | V                 |  |
| $V_{RRM}$  | max. repetitive reverse blocking voltage     | $T_{VJ} = 25^{\circ}C$                                |                         |         | 1200 | V                 |  |
| $I_R$      | reverse current                              | $V_R = 1200 V$  | $T_{VJ} = 25^{\circ}C$  |         | 100  | $\mu A$           |  |
|            |  | $V_R = 1200 V$  | $T_{VJ} = 150^{\circ}C$ |         | 2    | mA                |  |
| $V_F$      | forward voltage drop                         | $I_F = 50 A$  | $T_{VJ} = 25^{\circ}C$  |         | 1.13 | V                 |  |
|            |  | $I_F = 150 A$   |                         |         | 1.46 | V                 |  |
|            |  | $I_F = 50 A$  | $T_{VJ} = 125^{\circ}C$ |         | 1.04 | V                 |  |
|            |  | $I_F = 150 A$   |                         |         | 1.47 | V                 |  |
| $I_{DAV}$  | bridge output current                        | $T_C = 110^{\circ}C$<br>rectangular $d = \frac{1}{3}$ | $T_{VJ} = 150^{\circ}C$ |         | 125  | A                 |  |
| $V_{FO}$   | threshold voltage                            | } for power loss calculation only                     | $T_{VJ} = 150^{\circ}C$ |         | 0.79 | V                 |  |
| $r_F$      | slope resistance                             |   |                         |         | 4.5  | m $\Omega$        |  |
| $R_{thJC}$ | thermal resistance junction to case          |   |                         |         | 0.7  | K/W               |  |
| $R_{thCH}$ | thermal resistance case to heatsink          |   |                         | 0.3     |      | K/W               |  |
| $P_{tot}$  | total power dissipation                      |   | $T_C = 25^{\circ}C$     |         | 175  | W                 |  |
| $I_{FSM}$  | max. forward surge current                   | $t = 10 \text{ ms}; (50 \text{ Hz}), \text{ sine}$    | $T_{VJ} = 45^{\circ}C$  |         | 1.20 | kA                |  |
|            |  | $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{ sine}$   | $V_R = 0 V$             |         | 1.30 | kA                |  |
|            |  | $t = 10 \text{ ms}; (50 \text{ Hz}), \text{ sine}$    | $T_{VJ} = 150^{\circ}C$ |         | 1.02 | kA                |  |
|            |  | $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{ sine}$   | $V_R = 0 V$             |         | 1.10 | kA                |  |
| $I^2t$     | value for fusing                             | $t = 10 \text{ ms}; (50 \text{ Hz}), \text{ sine}$    | $T_{VJ} = 45^{\circ}C$  |         | 7.20 | kA <sup>2</sup> s |  |
|            |  | $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{ sine}$   | $V_R = 0 V$             |         | 6.98 | kA <sup>2</sup> s |  |
|            |  | $t = 10 \text{ ms}; (50 \text{ Hz}), \text{ sine}$    | $T_{VJ} = 150^{\circ}C$ |         | 5.20 | kA <sup>2</sup> s |  |
|            |  | $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{ sine}$   | $V_R = 0 V$             |         | 5.04 | kA <sup>2</sup> s |  |
| $C_J$      | junction capacitance                         | $V_R = 400 V; f = 1 \text{ MHz}$                      | $T_{VJ} = 25^{\circ}C$  |         | 37   | pF                |  |

| Package PWS-E |  |                      | Ratings |      |      |      |
|---------------|--|----------------------|---------|------|------|------|
| Symbol        | Definition   | Conditions           | min.    | typ. | max. | Unit |
| $I_{RMS}$     | RMS current  | per terminal         |         |      | 200  | A    |
| $T_{stg}$     | storage temperature  |                      | -40     |      | 125  | °C   |
| $T_{VJ}$      | virtual junction temperature                                 |                      | -40     |      | 150  | °C   |
| <b>Weight</b> |  |                      |         | 284  |      | g    |
| $M_D$         | mounting torque  |                      | 4.25    |      | 5.75 | Nm   |
| $M_T$         | terminal torque  |                      | 4.25    |      | 5.75 | Nm   |
| $d_{Spp/App}$ | creepage distance on surface   striking distance through air | terminal to terminal | 12.0    |      |      | mm   |
| $d_{Spt/Apb}$ |  | terminal to backside | 26.0    |      |      | mm   |
| $V_{ISOL}$    | isolation voltage  | t = 1 second         | 3000    |      |      | V    |
|               |  | t = 1 minute         | 2500    |      |      | V    |



| Ordering | Part Number  | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|--------------|--------------------|---------------|----------|----------|
| Standard | VUO110-12NO7 | VUO110-12NO7       | Box           | 5        | 462373   |

### Equivalent Circuits for Simulation

\* on die level

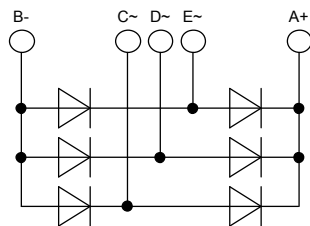
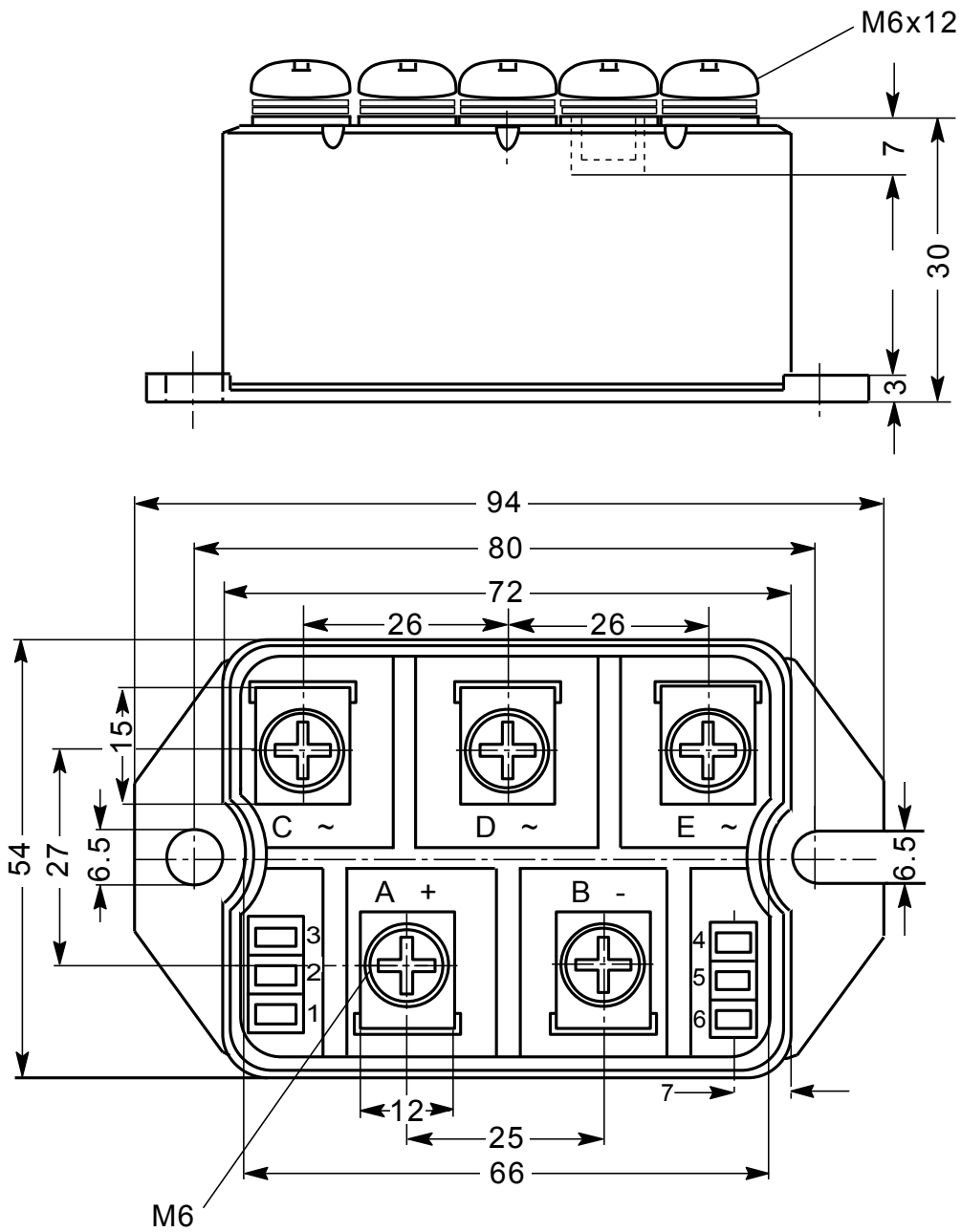
$T_{VJ} = 150\text{ °C}$



Rectifier

|              |                    |      |    |
|--------------|--------------------|------|----|
| $V_{0\ max}$ | threshold voltage  | 0.79 | V  |
| $R_{0\ max}$ | slope resistance * | 3.3  | mΩ |

**Outlines PWS-E**



Rectifier

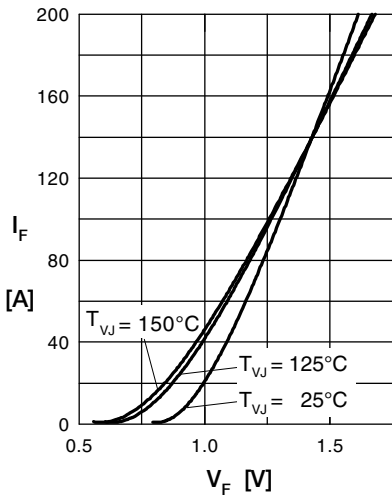


Fig. 1 Forward current vs. voltage drop per diode

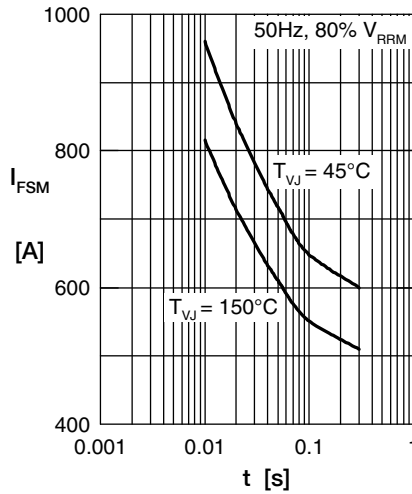


Fig. 2 Surge overload current vs. time per diode

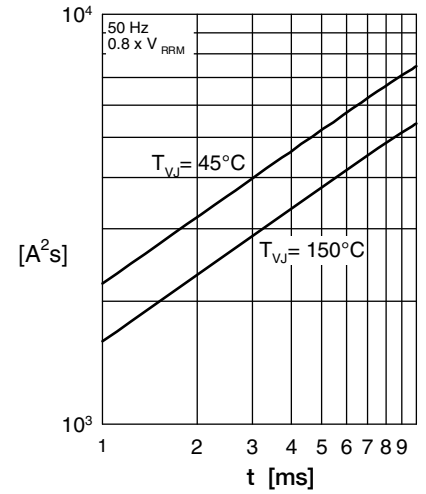


Fig. 3  $I^2t$  vs. time per diode

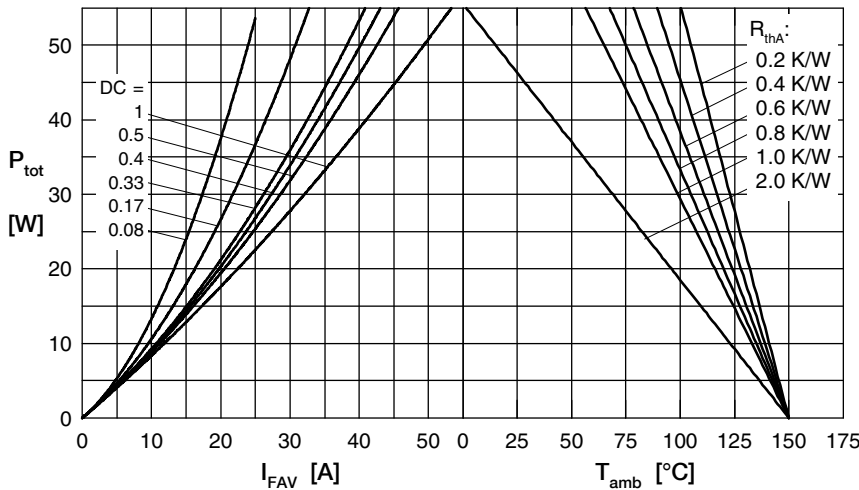


Fig. 4 Power dissipation vs. forward current and ambient temperature per diode

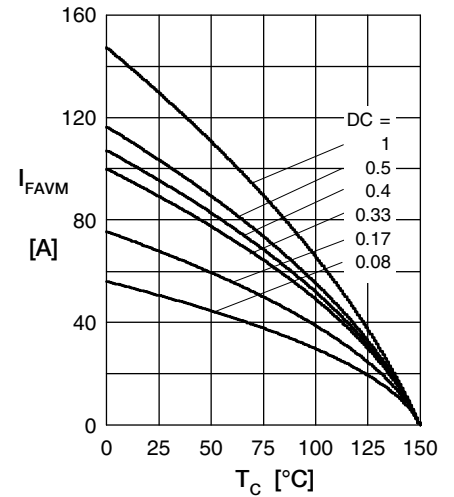


Fig. 5 Max. forward current vs. case temperature per diode

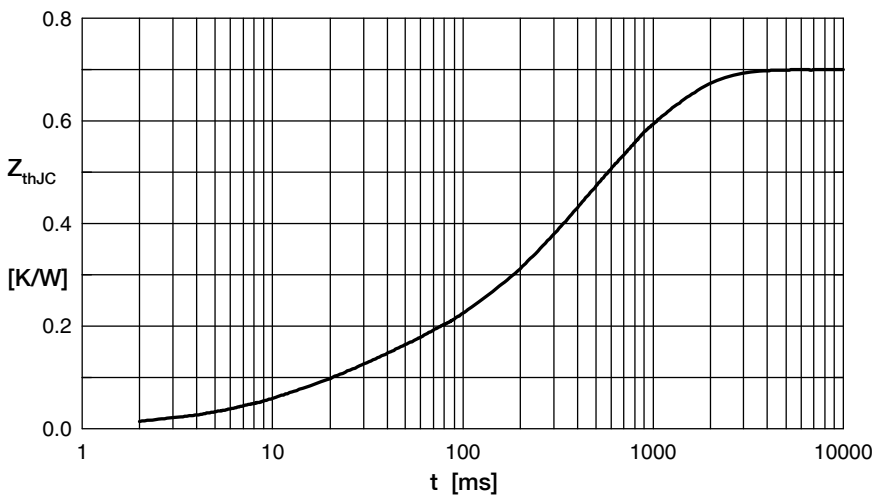


Fig. 6 Transient thermal impedance junction to case vs. time per diode

| $R_i$ | $t_i$ |
|-------|-------|
| 0.100 | 0.020 |
| 0.010 | 0.010 |
| 0.162 | 0.225 |
| 0.258 | 0.800 |
| 0.170 | 0.580 |

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